

# Strong Entropic Contributions to Thermallyactivated Kinetics: A Case-study in Dislocation Nucleation

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IPAM Long Program: <u>New Mathematics for the Exascale: Applications to Materials Science</u> Workshop I: Increasing the Length, Time, and Accuracy of Materials Modeling Using Exascale Computing

### **Dislocations Multiplication from Pre-Existing Sources**



- Strength and ductility of crystals is dictated by plastic response
- Strain is accommodated through slip, beyond elastic level

### Nucleations of *new* dislocations are rare (?)



- Strength and ductility of crystals is dictated by plastic response
- Strain is accommodated through slip, beyond elastic level
- Typical crystal microstructures posses pre-existing defects
- Nano-/micro-pillars could be "almost" defect free



Chen et al. 2015



Greer J. et al., 2005

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- Typical crystal microstructures posses pre-existing defects
- Nano-/micro-pillars could be "almost" defect free
- Nucleation of new dislocations from stress concentrators govern onset of plasticity



Chen et al. 2015



Greer J. et al., 2005

#### **Surface Nucleation Pathways: How Feasible are they?**

under low (2%) compressive strain



Nudged Elastic Band (NEB) Search of Minimum Energy Path (MEP)



From TST based approximations,

An upper bound for rate (i.e. no recrossing)

$$k = \frac{K_B T}{h} \frac{Z^*}{Z_A}$$

$$= \frac{\prod_{i=1}^{3N} v_i^A}{\prod_{i=1}^{3N-1} v_i^*} e^{\frac{-E_b}{K_B T}} \text{ Harmonic Approx}$$

$$= v_0 e^{\frac{-E_b}{K_B T}}$$
(Arrhenius rate)



From TST based approximations,

An upper bound for rate (i.e. no recrossing)



#### **Surface Nucleation Events from MD Simulations**



under low (2%) compressive strain



With ~40 Million EAM Cu atoms

(only defect-atoms are shown)

(10K/ns)





#### **Maximum Likelihood of Rate Parameters**

From a series of (~100) 40 million atom MD runs



According to rate theories,

 $p_i(t) \sim k(t)e^{-\int k(t)dt}$ , where  $k(t) = v_0 e^{\frac{-E_b}{K_B T(t)}}$  $\sim p(t, v, E_b)$ 

considering MD runs as i.i.d

$$L(v, E_b | t_{nuc}) = \prod_i p_i$$

#### **Maximum Likelihood of Rate Parameters**





#### **Maximum Likelihood of Rate Parameters**

From a series of (~100) 40 million atom MD runs



 $p_i(t)dt \sim \text{ probability of nucleating between time } t$ and t + dt $p_i(t) \sim k(t)e^{-\int k(t)dt}, \text{ where } k(t) = v_0 e^{\frac{-E_b}{K_BT(t)}}$  $\sim p(t, v, E_b)$ 

considering MD runs as i.i.d

$$L(v, E_b | t_{nuc}) = \prod_i p_i$$

But  $10^{32} - 10^{33}$  /s is huge w.r.t typical prefactors of  $10^{12}$  /s



4.5

From TST based approximations,

An upper bound for rate (i.e. no recrossing)

$$k = \frac{K_B T}{h} \frac{Z^*}{Z_A}$$



N is usually a large number → which means a small change in frequency multiplicatively high!

$$= v_0 \ e^{\frac{S}{K_B}} e^{\frac{-E_b}{K_BT}}$$



From TST based approximations,

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$$k = \frac{K_B T}{h} \frac{Z^*}{Z_A}$$

$$=\frac{\prod_{i=1}^{3N}v_i^A}{\prod_{i=1}^{3N-1}v_i^*}e^{\frac{-E_b}{K_BT}}=\frac{Harmonic\,Approx.}{$$

N is usually a large number -> which means a small change in frequency multiplicatively high!

$$= v_0 e^{\frac{S}{K_B}} e^{\frac{-E_b}{K_BT}}$$
$$-(F^* - F^A)$$

 $\sim ve^{-K_BT}$ 

Need:

Hessian at minimum and saddle

#### But:

• Computationally expensive (Typically million atoms systems)



From TST based approximations,

ZΔ

 $E_{barrier}$ 

An upper bound for rate (i.e. no recrossing)

$$k = \frac{K_B T}{h} \frac{Z^*}{Z_A}$$

$$=\frac{\prod_{i=1}^{3N}v_i^A}{\prod_{i=1}^{3N-1}v_i^*}e^{\frac{-E_b}{K_BT}}=\frac{Harmonic\,Approx.}{Harmonic\,Approx.}$$

N is usually a large number  $\rightarrow$  which means a small change in frequency *multiplicatively high!* 

$$= v_0 e^{\frac{S}{K_B}} e^{\frac{-E_b}{K_B T}}$$
$$\sim v_0 e^{\frac{-(F^* - F^A)}{K_B T}}$$

 $\sim ve$ 

#### Finite T-string/PAFI methods to compute free energy—but still involved!

#### Need:

Hessian at minimum and  $\bullet$ saddle

#### **But:**

Computationally expensive • (Typically million atoms systems)

#### **Entropy computation from higher order free-energy approximation**

Following Schroek 1980,

Higher order approx. of free-energy density as function of temp. (*T*) and Green-Lagrange strain  $E_{ij} = \frac{1}{2} [F_{ik}F_{kj} - \delta_{ij}]$ 

$$f(T, E_{ij}) = f_0 + f_{T,ik}TE_{ik} + \frac{1}{2}f_{ik,lm}E_{ik}E_{lm} + \dots$$

Higher order entropy density

$$\Delta s = -\frac{\partial \Delta f}{\partial T} = -f_{T,ik}E_{ik} - \frac{1}{2}f_{T,ik,lm}E_{ik}E_{lm} = \alpha_{lm}f_{ik,lm}E_{ik} - \frac{1}{2}f_{T,ik,lm}E_{ik}E_{lm}$$

Total Entropy change

$$S = \int \Delta s dV = \alpha_V K \int E_{ii} dV - \frac{1}{2} \frac{\partial C_{iklm}}{\partial T} \int E_{ik} E_{lm} dV$$
  
Thermal expansion  
coefficient T-dependences of  
elastic modulii

![](_page_14_Figure_8.jpeg)

### Free Energy along MEP : under compression

![](_page_15_Figure_1.jpeg)

### Free Energy along MEP : under compression

Total Entropy change  $S = \alpha_V K \left| \int E_{ii} dV \right| - \frac{1}{2} \frac{\partial C_{iklm}}{\partial T} \int E_{ik} E_{lm} dV \qquad \mathcal{F} = E - TS$ Z\* (?  $\frac{K_BT}{h} \frac{Z^*}{Z_A}$ 10144  $\boldsymbol{k} =$ OK (NEB) 6 10124 100K Energy (eV) 10<sup>104</sup> 10<sup>84</sup> With increasing T: rc = 0.075Free rc = 0.05Free energy saddle moves inwards • entropy 300K 4e-06 2 (towards smaller loops) Free energy barrier becomes smaller 650K might need to consider variations of rc = 0.1251e-06 0.3 saddle/dividing surface? 0.2 0.0 0.1 **Reaction Coordinate** 

**1 0** 8

# **Variational Transition State Theory**

The "best" dividing surface is the one the predicts the smallest TST rate (since TST is an upper bound to the true rate)

I.e., the (T-dependent) dividing surface should be at the **free-energy saddle**, not the energy saddle

![](_page_17_Picture_3.jpeg)

#### **Free Energy Pathway for Dislocation Nucleation**

Total Entropy change

![](_page_18_Figure_2.jpeg)

#### **Free Energy Pathway for Dislocation Nucleation**

Total Entropy change

![](_page_19_Figure_2.jpeg)

Bagchi S Perez D., 2022 (in preperation)

#### Variational TST can capture anharmonic kinetic rates

 $v_0 e^{\frac{S}{K_B}} e^{\frac{-E_b}{K_BT}}$ 

![](_page_20_Figure_2.jpeg)

HTST is asymptotically recovered at low-T and high compressive strains

#### Vibrational Entropy could be crucial for plasticity

#### Summary:

![](_page_21_Figure_2.jpeg)

We have implemented a continuum approximation to the entropy change that predicts:

Free energy barriers << Energy barriers HUGE prefactors (10<sup>32</sup> vs 10<sup>12</sup> 1/s ! ) Nucleation rates in good agreement with direct MD

Data-driven ways to quantify path deviations at finite–T (also benchmanrk with other methods e.g. PAFI)

Strong anharmonicity can also facilitate other activated plasticity (large strain release) events

![](_page_21_Figure_7.jpeg)

# Acknowledgements

![](_page_22_Picture_1.jpeg)